

# TO-252-2L Plastic-Encapsulate Transistors

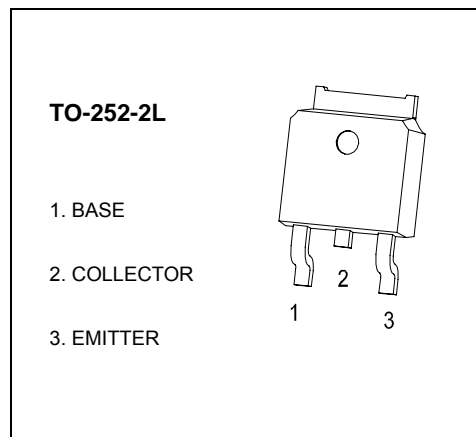
TRANSISTOR (PNP)

## FEATURES

High DC Current Gain  
Electrically Similar to Popular  
Built-in a Damper Diode at E-C

## MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CB0</sub>	Collector-Base Voltage	-100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-100	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current -Continuous	-8	A
P <sub>C</sub>	Collector Power Dissipation	1.5	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55-150	°C

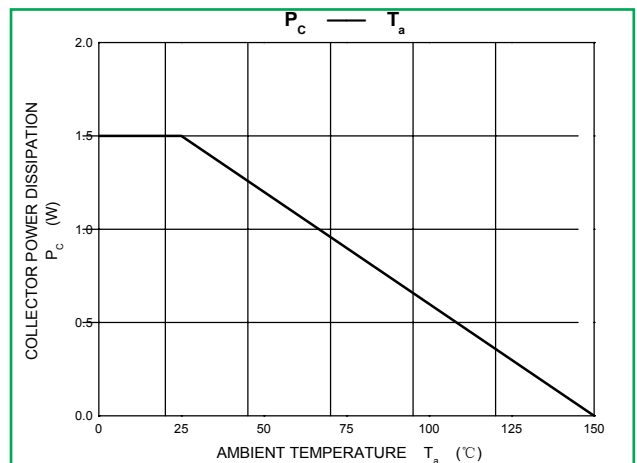
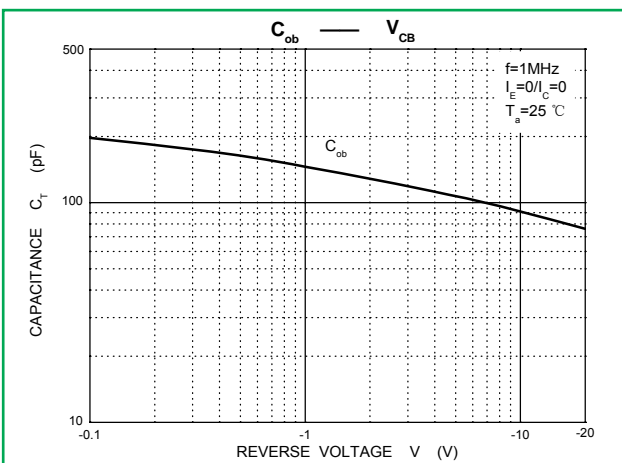
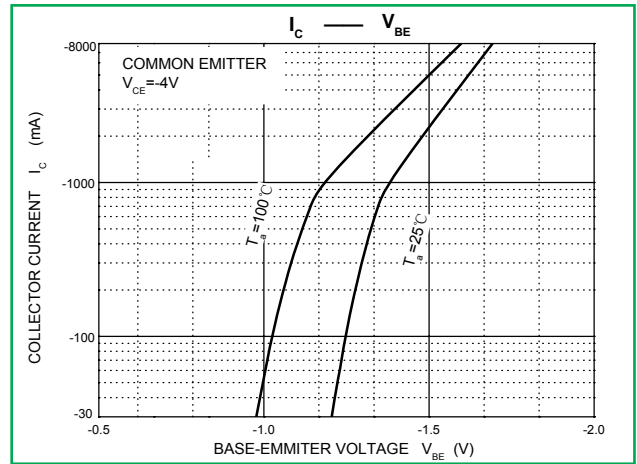
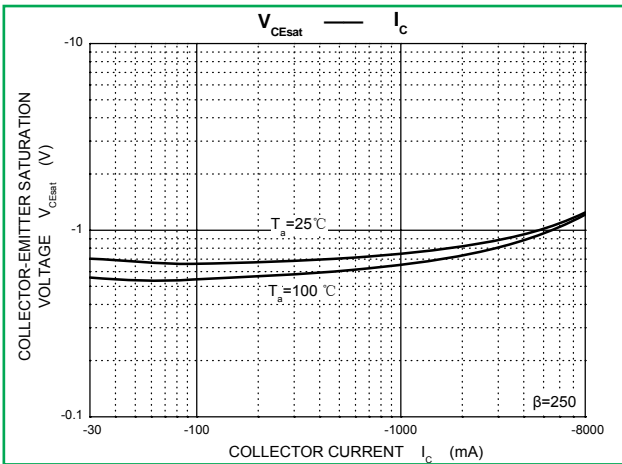
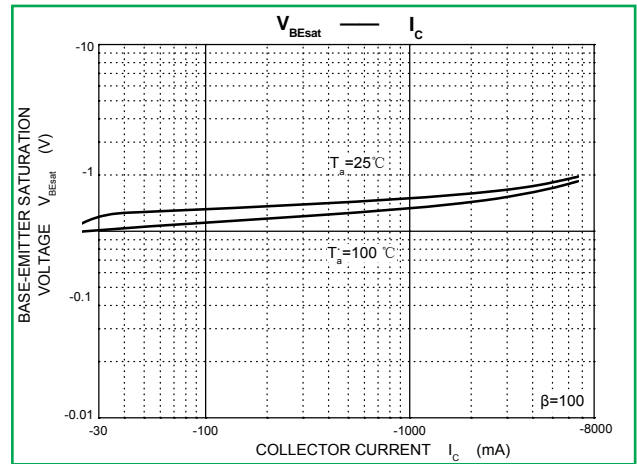
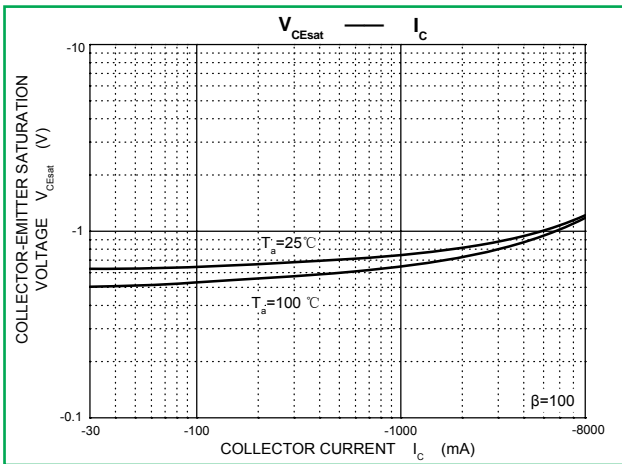
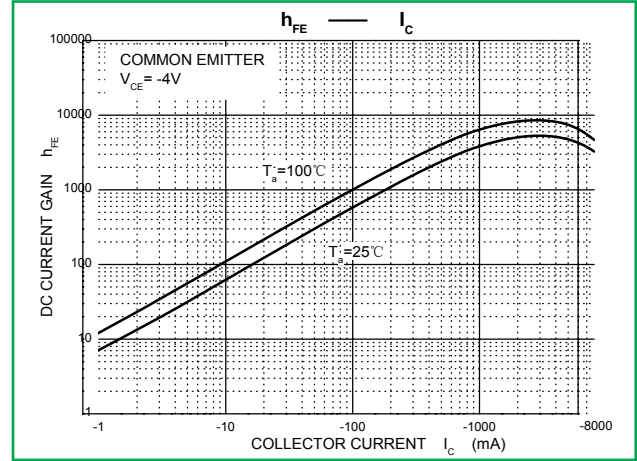
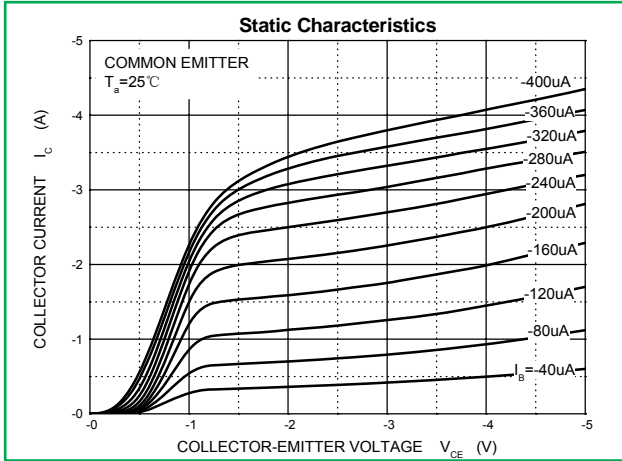


## ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)

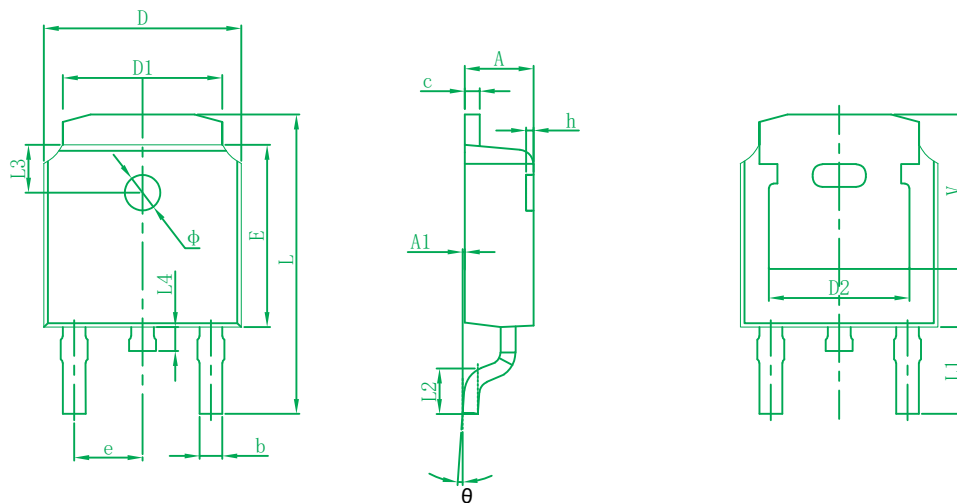
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-1mA, I <sub>E</sub> =0	-100			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-30mA, I <sub>B</sub> =0	-100			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-10mA, I <sub>C</sub> =0	-5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =-100V, I <sub>E</sub> =0			-10	μA
Collector-emitter cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =-50V, I <sub>B</sub> =0			-10	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =-5V, I <sub>C</sub> =0			-2	mA
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =-4V, I <sub>C</sub> =-4A	1000		12000	
	h <sub>FE(2)</sub>	V <sub>CE</sub> =-4V, I <sub>C</sub> =-8A	100			
Collector-emitter saturation voltage	V <sub>CE(sat) 1</sub> *	I <sub>C</sub> =-4A, I <sub>B</sub> =-16mA			-2	V
	V <sub>CE(sat) 2</sub> *	I <sub>C</sub> =-8A, I <sub>B</sub> =-80mA			-4	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub> *	I <sub>C</sub> =-8A, I <sub>B</sub> =-80mA			-4.5	V
Base-emitter voltage	V <sub>BE</sub> *	V <sub>CE</sub> =-4V, I <sub>C</sub> =-4A			-2.8	V
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V, I <sub>E</sub> =0, f=0.1MHz			300	pF

\*Pulse Test: Pulse Width≤380μs, Duty Cycle≤2%

# Typical Characteristics

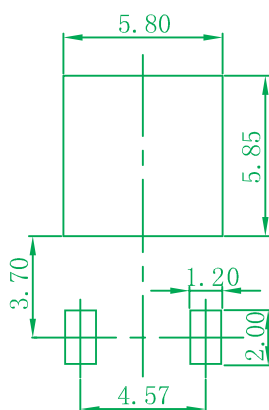


## TO-252-2L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.635	0.770	0.025	0.030
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.712	10.312	0.382	0.406
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.250 REF.		0.207 REF.	

## TO-252-2L Suggested Pad Layout



## Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05$  mm.
3. The pad layout is for reference purposes only.